

## Description

The ST0561N4 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The ST0561N4 complies with the IEC 61000-4-2 (ESD) standard with  $\pm 15\text{kV}$  air and  $\pm 8\text{kV}$  contact discharge. It is assembled into an ultra-small  $1.0 \times 0.6 \times 0.5\text{mm}$  lead-free DFN package. The small size, ultra-low capacitance and high ESD surge protection make ST0561N4 an ideal choice to protect cell phone, digital video interfaces.

## Features

- ◆ Ultra small package:  $1.0 \times 0.6 \times 0.5\text{mm}$
- ◆ Low leakage: nA level
- ◆ Low operating voltage: 5V
- ◆ Low clamping voltage
- ◆ 2-pin leadless package
- ◆ Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test  
Air discharge:  $\pm 30\text{kV}$   
Contact discharge:  $\pm 30\text{kV}$
  - IEC61000-4-4 (EFT) 40A (5/50ns)
  - IEC61000-4-5 (Lightning) 8A (8/20 $\mu\text{s}$ )
- ◆ RoHS Compliant

## Mechanical Characteristics

- ◆ Package: DFN1006-2
- ◆ Lead Finish: NiPdAu
- ◆ Case Material: “Green” Molding Compound.
- ◆ UL Flammability Classification Rating 94V-0
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

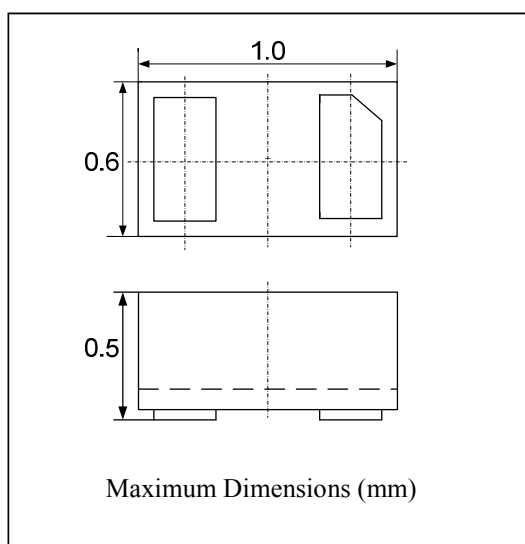
## Applications

- ◆ Personal Digital Assistants
- ◆ Peripherals
- ◆ Audio Players
- ◆ Notebooks and Handhelds
- ◆ Portable Instrumentation
- ◆ Keypads, Side Keys, LCD Displays

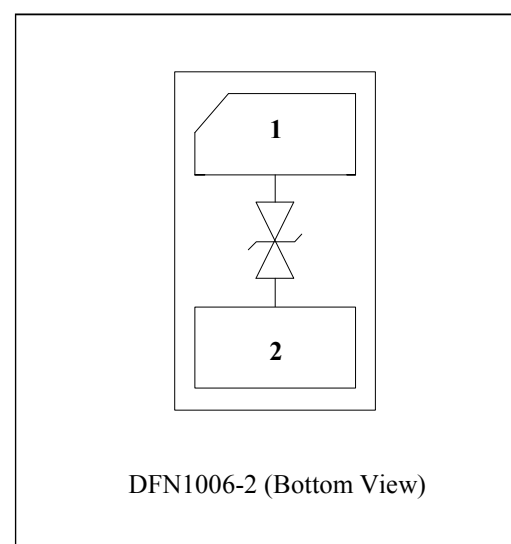
## Ordering Information

Part Number	Packaging	Reel Size
ST0561N4	10000/Tape & Reel	7 inch

## Dimensions



## Schematic and PIN Configuration



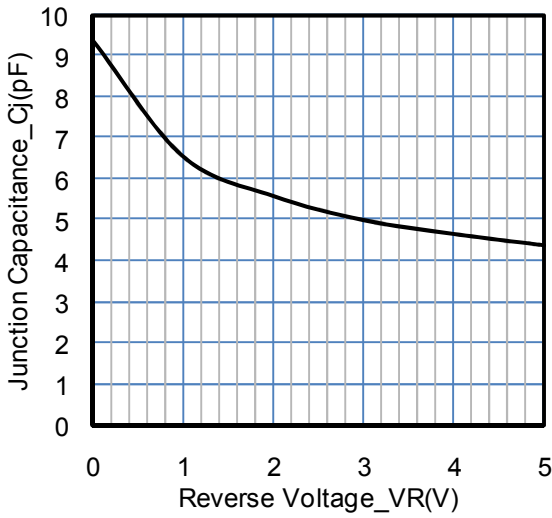
**Absolute Maximum Ratings (TA=25°C unless otherwise specified)**

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	80	W
Peak Pulse Current (8/20μs)	IPP	8	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

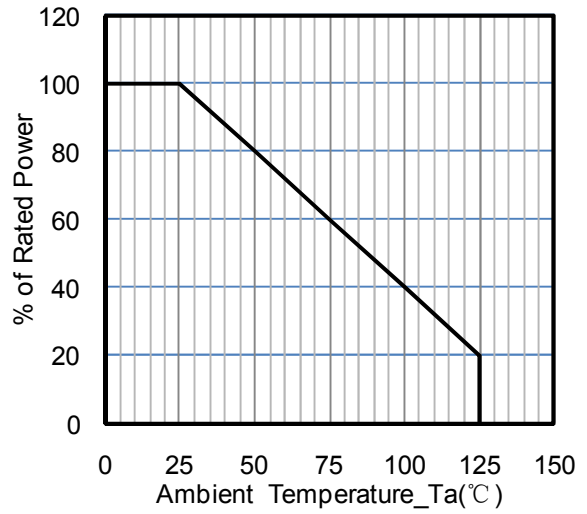
**Electrical Characteristics (TA=25°C unless otherwise specified)**

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	6.5	7.2	8	V	IT = 1mA
Reverse Leakage Current	IR			0.5	uA	VRWM = 5V
Clamping Voltage	VC			7	V	IPP = 1A (8 x 20μs pulse)
Clamping Voltage	VC			10	V	IPP = 8A (8 x 20μs pulse)
Junction Capacitance	CJ		15	18	pF	VR = 0V, f = 1MHz

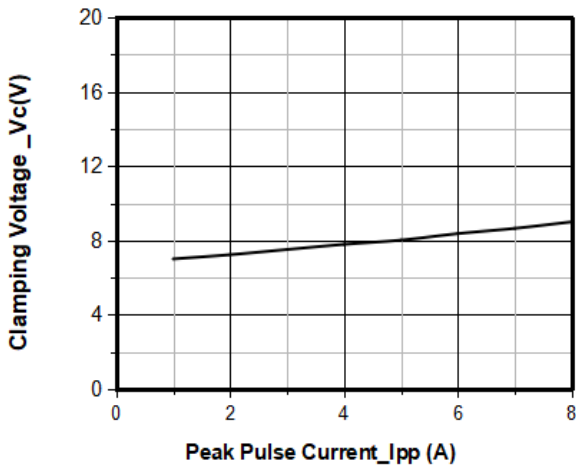
Typical Performance Characteristics (TA=25°C unless otherwise specified)



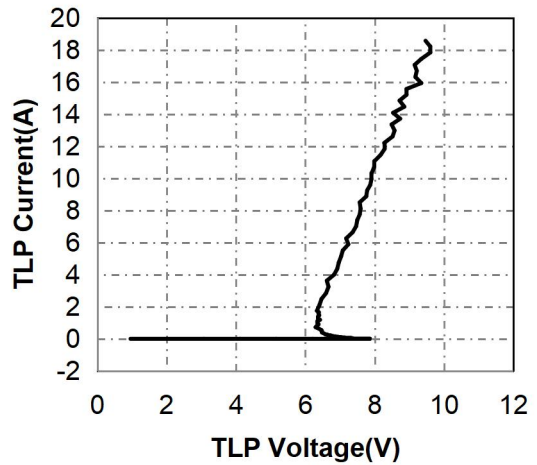
Junction Capacitance vs. Reverse Voltage



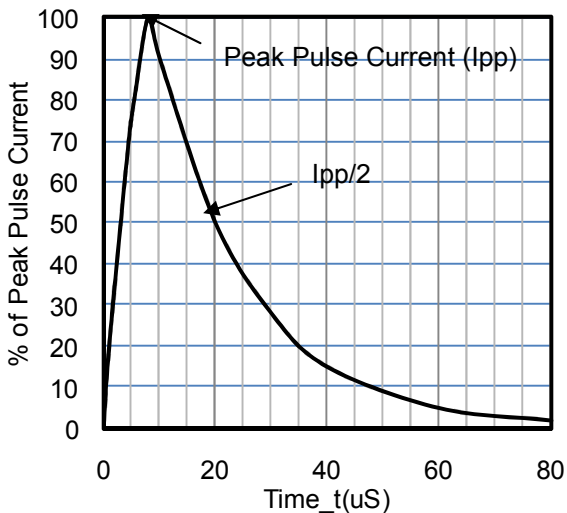
Power Derating Curve



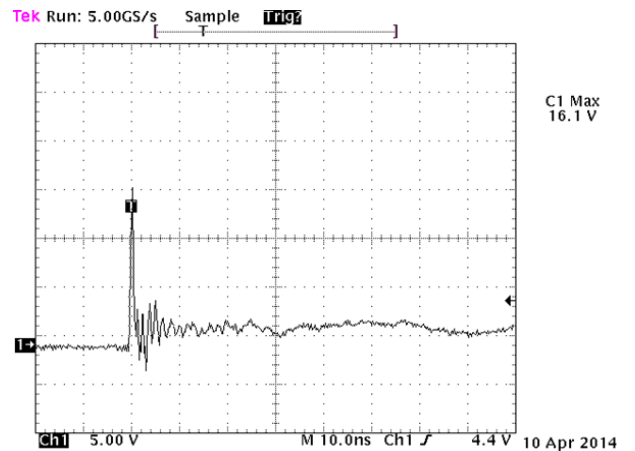
Clamping Voltage vs. Peak Pulse Current ( $t_p = 8/20\mu s$ )



Transmission Line Pulse (TLP)



8 X 20μs Pulse Waveform



Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

8 kV Contact per IEC61000-4-2

## Applications Information

### Device Connection Options

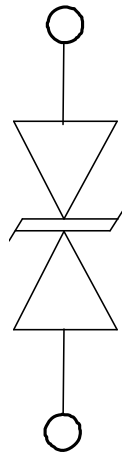
These low capacitance TVS diodes are designed to provide common mode protection for one high-speed line or differential protection for one line pair. The device is bidirectional and may be used on lines where the signal polarity is positive and negative.

### Circuit Board Layout Recommendations for Suppression of ESD

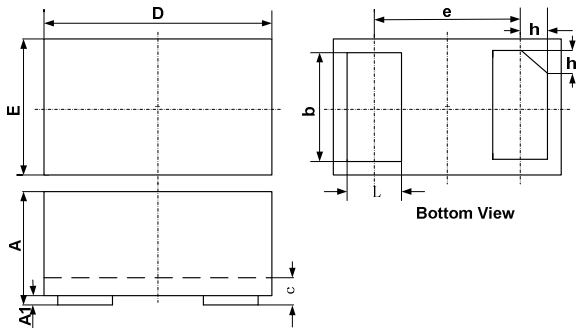
Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

- ◆ Place the TVS near the input terminals or connectors to restrict transient coupling.
- ◆ Minimize the path length between the TVS and the protected line.
- ◆ Minimize all conductive loops including power and ground loops.
- ◆ The ESD transient return path to ground should be kept as short as possible.
- ◆ Never run critical signals near board edges.
- ◆ Use ground planes whenever possible.

### Equivalent Circuit Diagram

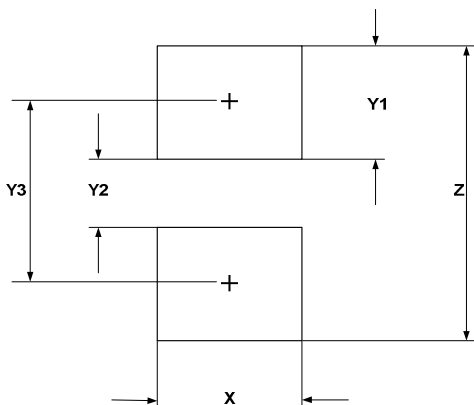


## DFN1006-2 Package Outline Drawing



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

## Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	0.60	0.024
Y1	0.50	0.020
Y2	0.30	0.012
Y3	0.80	0.032
Z	1.30	0.052

## Contact Information

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